Overload Monitoring with Resistive Load, $V_T = 44.5 \text{ mV}$

Description

The IC U4793B in bipolar circuit, is designed to monitor overload or a short circuit in automotive or industrial applications. The threshold is tied to $V_{4,6} = V_S - V_T$ whereas $V_T = 44.5$ mV. It is independent of the supply voltage, V_S . If the voltage drop across shunt resistor, R_{sh} , exceeds this value, the output is turned on, otherwise the output is turned off.

Without supply voltage or open input Pin 8, the output is turned off. The output breakdown voltage is determined by the Z-diodes Z_3 and Z_5 with a typical value of $V_Z = 22$ V.

A not used comparator input must be connected to Pin 7.

Features

- 10 kV ESD protection
- Two comparators with common reference
- Tight threshold tolerance
- Constant threshold
- NPN output

Block Diagram

- Interference and damage-protection according to VDE 0839
- EMI protection
- Reversal polarity protection
- Load dump protection

Case: DIP 8 and SO 8

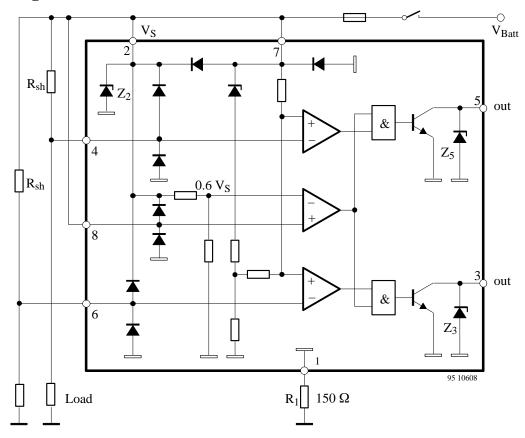
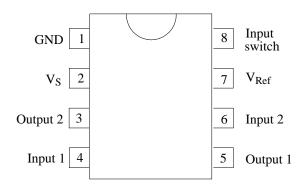


Figure 1. Schematic and application circuit

U4793B/ U4793B-FP

Pin Description



Pin	Symbol	Function		
1	GND	Reference point, ground		
2	Vs	Supply voltage		
3	O ₂	Output 2		
4	I ₁	Input 1		
5	O1	Output 1		
6	I ₂	Input 2		
7	V _{Ref}	Reference voltage		
8	Input	Input switch		

Absolute Maximum Ratings

Parameters			Symbol	Value	Unit
Supply voltage Pin 2, 7			Vs	16.5	V
Current consumption					
t = 2 ms, measured at Pin 1 (GND) Pin 1			I ₁	1.5	А
Output current Pin			I _{3,5}	20	mA
Input voltage	Pin 4, 6				
reference point Pin 7			$-V_{4,6}$	6	V
Power dissipation					
$T_{amb} = 95 \ ^{\circ}C$	DIP 8		P _{tot}	420	mW
	SO 8			360	
$T_{amb} = 60 \ ^{\circ}C$	DIP 8		P _{tot}	690	mW
	SO 8			560	
Ambient temperature range			T _{amb}	-40 to +95	°C
Storage temperature range			T _{stg}	-55 to +125	°C
Junction temperature			Ti	150	°C

Electrical Characteristics

$V_{\rm S} = 9$ to 15 V, $T_{\rm amb} = -40$ to	o +95 °C, figure 1.	unless otherwise specified
S and		

Parameters	Test Conditions / Pir	n	Symbol	Min	Тур	Max	Unit
Supply voltage	Pin	n 2,7	Vs	9		15	V
Internal Z diode Z ₂	Pin	n 2	VZ	20			V
Current consumption	$V_{S} = 12 V$ Pin measured at Pin 1 (GND		I ₁		4.5	6	mA
Output saturation voltage	$V_S = 9 V$, $I_{3,5} = 10 mA$ $T_{amb} = 25 °C$ Pin	n 3,5	V _{sat}			0.5	v
Output Z diodes Z ₃ , Z ₅	Pin	n 3,5	VZ	21			V
Control signal threshold	$I_{3,5} = 1 \text{ mA}$, figure 3 Pir $T_{amb} = 25^{\circ}C$	1 4,6	-V _T	43	44.5	46	mV
Temperature coefficient of control signal threshold			TC		15		μV/K
Threshold voltage	Switch identification Pir	n 8	V ₈		0.6 V _S		V
Input currents	Pir	n 4,6	II		100		nA
	Pin	18			5		μΑ
Delay time	Switch-on Pin High to low	n 3,5	t _{d(on)}		6		μs
	Switch-off Low to high		t _{d(off)}		30		μs

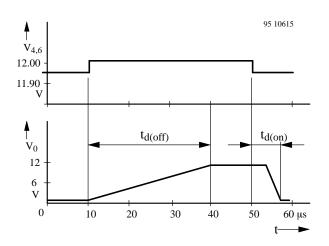


Figure 2.

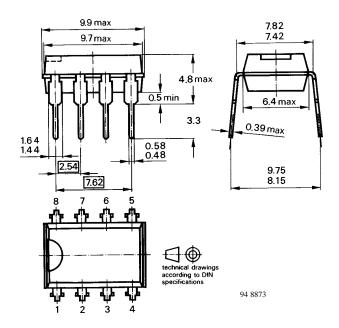
Figure 3.

U4793B/ U4793B-FP

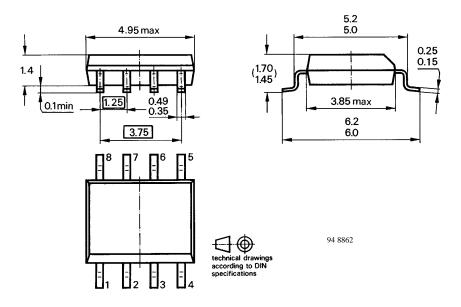
TELEFUNKEN Semiconductors

Dimensions in mm

Package: DIP 8



Package: SO 8



Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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